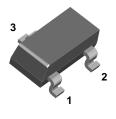
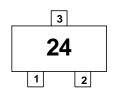


# MMBD1201 / 1203 / 1204 / 1205

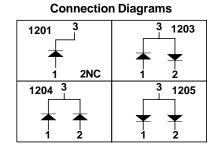






### MARKING MMBD1201 24

MMBD1203 26 MMBD1204 27 MMBD1205 28



# **Small Signal Diodes**

**Absolute Maximum Ratings\*** 

T<sub>a</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{RRM}$	Maximum Repetitive Reverse Voltage	100	V
I <sub>F(AV)</sub>	Average Rectified Forward Current	200	mA
I <sub>FSM</sub>	Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 second Pulse Width = 1.0 microsecond	1.0 2.0	A A
T <sub>stg</sub>	Storage Temperature Range	-55 to +150	°C
T <sub>J</sub>	Operating Junction Temperature	150	°C

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### **Thermal Characteristics**

Symbol	Parameter	Value	Units
$P_{D}$	Power Dissipation	350	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

## **Electrical Characteristics** T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
$V_R$	Breakdown Voltage	I <sub>R</sub> = 100 μA	100		V
V <sub>F</sub>	Forward Voltage	$I_{F} = 1.0 \text{ mA}$ $I_{F} = 10 \text{ mA}$ $I_{F} = 100 \text{ mA}$ $I_{F} = 200 \text{ mA}$ $I_{F} = 300 \text{ mA}$	550 660 820 0.87	600 740 920 1.0 1.1	mV mV mV V
I <sub>R</sub>	Reverse Current	$V_R = 20 \text{ V}$ $V_R = 50 \text{ V}$ $V_R = 50 \text{ V}, T_A = 150^{\circ}\text{C}$		25 50 5.0	nA nA μA
C <sub>T</sub>	Total Capacitance	$V_R = 0$ , $f = 1.0 \text{ MHz}$		2.0	pF
t <sub>rr</sub>	Reverse Recovery Time	$I_F = I_R = 10 \text{ mA}, I_{RR} = 1.0 \text{ mA},$ $R_L = 100 \Omega$		4.0	ns

<sup>1)</sup> These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

## **Small Signal Diode**

(continued)

### **Typical Characteristics**

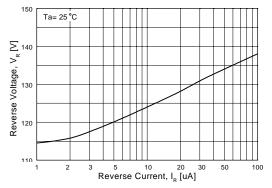


Figure 1. Reverse Voltage vs Reverse Current BV - 1.0 to 100uA

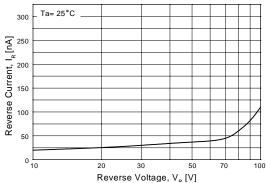


Figure 2. Reverse Current vs Reverse Voltage IR - 10 to 100 V

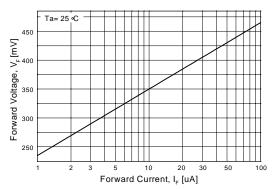


Figure 3. Forward Voltage vs Forward Current VF - 1.0 to 100 uA

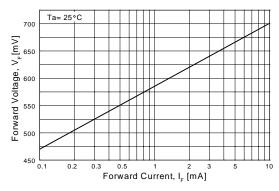


Figure 4. Forward Voltage vs Forward Current VF - 0.1 to 10 mA

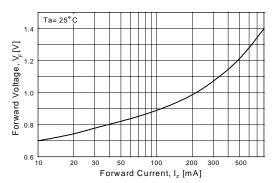


Figure 5. Forward Voltage vs Forward Current VF - 10 - 800 mA

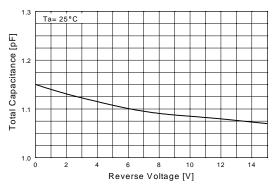


Figure 6. Total Capacitance vs Reverse Voltage

## **Small Signal Diode**

(continued)

# Typical Characteristics (continued)

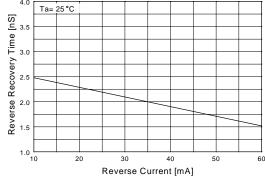


Figure 7. Reverse Recovery Time vs Reverse Current TRR - IR 10 mA vs 60 mA

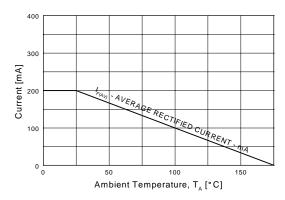


Figure 8. Average Rectified Current ( $I_{F(AV)}$ ) versus Ambient Temperature ( $T_A$ )

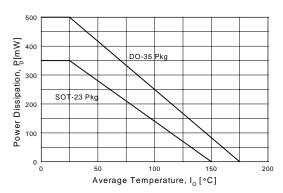


Figure 9. Power Derating Curve

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